

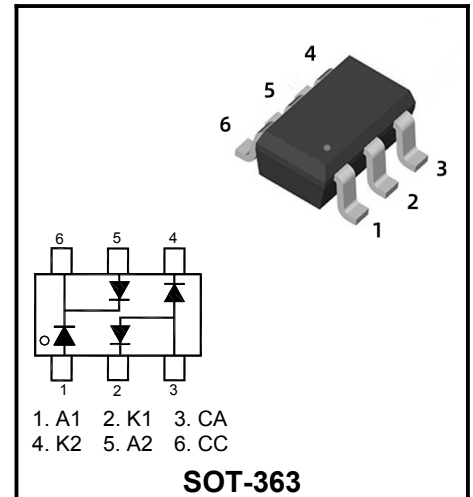
**Silicon Epitaxial Planar Switching Diode**

**Features**

- High speed
- High switching speed

**Marking Code**

<b>Marking Code</b>	
<b>BAV756DW</b>	<b>.KCA</b>



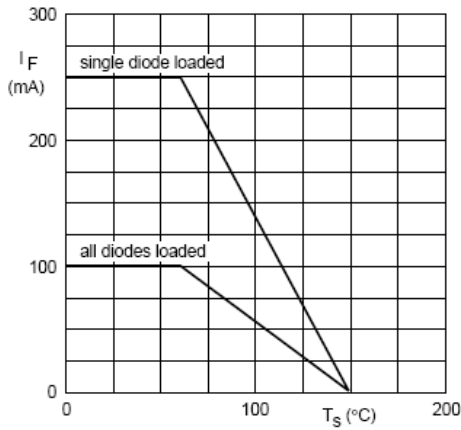
**Absolute Maximum Ratings (Ta=25°C)**

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	90	V
Reverse Voltage	$V_R$	90	V
Continuous Forward Current	$I_F$	250	mA
Single Diode Loaded All Diodes Loaded		100	
Repetitive Peak Forward Current	$I_{FRM}$	500	mA
Non-Repetitive Peak Forward Surge Current	$I_{FSM}$	4	A
at t = 1 $\mu$ s		1	
at t = 1 ms at t = 1 s		0.5	
Total Power Dissipation	$P_{tot}$	350	mW
Junction Temperature	$T_j$	- 65 to + 150	°C
Storage Temperature Range	$T_{stg}$	- 65 to + 150	°C

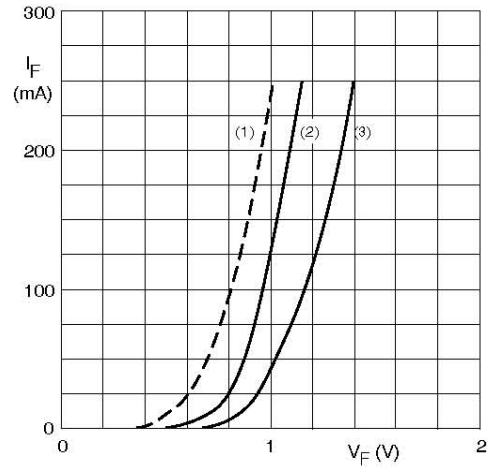
**Electrical Characteristics (Ta=25°C unless otherwise specified.)**

Parameter	Symbol	Max.	Unit
Forward Voltage at $I_F = 1$ mA at $I_F = 10$ mA at $I_F = 50$ mA at $I_F = 150$ mA	$V_F$	0.715	V
		0.855	
		1	
		1.25	
Reverse Current at $V_R = 25$ V at $V_R = 80$ V at $V_R = 25$ V, $T_j = 150^\circ\text{C}$ at $V_R = 80$ V, $T_j = 150^\circ\text{C}$	$I_R$	30	nA
		0.5	$\mu$ A
		30	$\mu$ A
		150	$\mu$ A
Diode Capacitance at $V_R = 0$ , f = 1 MHz	$C_d$	2	pF
Reverse Recovery Time at $I_F = I_R = 10$ mA, $t_{rr} = 0.1 \times I_R$ , $R_L = 100 \Omega$	$t_{rr}$	4	ns

**Typical Characteristics**

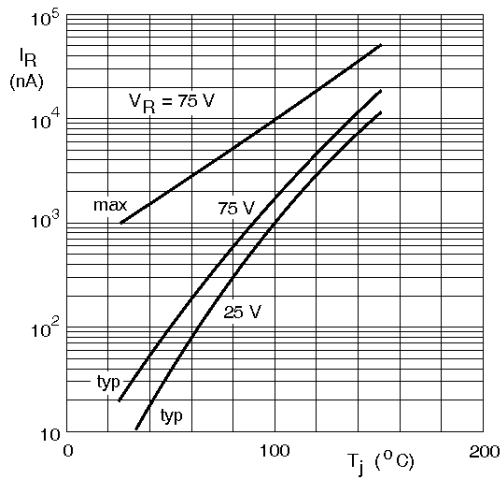


Maximum permissible continuous forward current as a function of soldering point temperature.

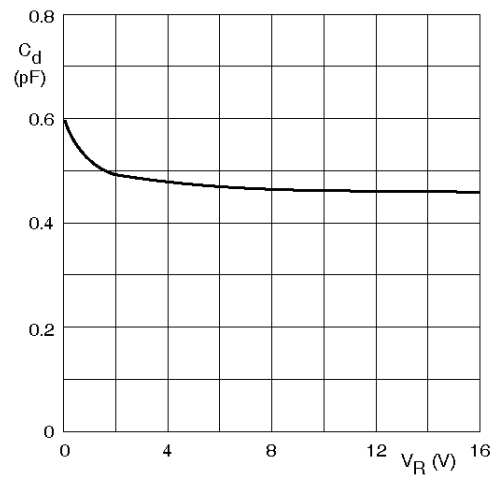


- (1)  $T_j = 150^\circ\text{C}$ ; typical values.
- (2)  $T_j = 25^\circ\text{C}$ ; typical values.
- (3)  $T_j = 25^\circ\text{C}$ ; maximum values.

Forward current as a function of forward voltage.



Reverse current as a function of junction temperature.



$f = 1\text{ MHz}$ ;  $T_j = 25^\circ\text{C}$ .

Diode capacitance as a function of reverse voltage; typical values.

**Ordering information**

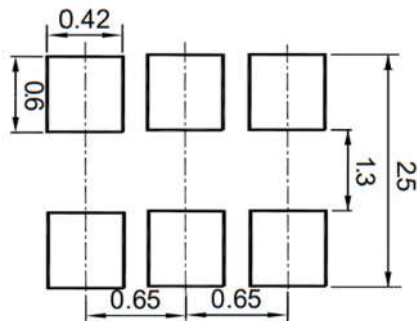
Package	Packing Description	Packing Quantity
SOT-363	Tape/Reel, 7" reel	3000PCS/Reel 120000PCS/Carton

**Package Dimensions**

**SOT-363**

Dim.	Millimeter(mm)		mil	
	Min.	Max.	Min.	Max.
A	0.8	1.1	32	43
A1	-	0.1	-	3.94
bp	0.20	0.30	7.87	11.81
c	0.10	0.25	3.94	9.84
D	1.8	2.2	70.87	86.61
E	1.15	1.35	45.28	53.15
e	1.3		51.18	
e1	0.65		25.6	
HE	2.0	2.2	78.74	86.6
Lp	0.15	0.45	5.90	17.71
Q	0.15	0.25	5.90	9.84
v	0.2		7.78	
w	0.2		7.78	
y	0.1		3.94	

**The recommended mounting pad size**



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